

Triple-Junction Terrestrial Concentrator Solar Cells

Features

- High efficiency GaInP₂/GaAs/Ge triple junction monolythic, two-terminal design
- Greater than 30% AM1.5D min. avg. efficiency from 200 to 400 Suns concentration in production
- Compatible with point focus, dense array and linear concentrators
- High Reliability

-No degradation with multiple assembly methods

Product Description

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Substrate	Germanium		
Method of Cell Growth	Metal Organic Vapor Phase Epitaxy		
Polarity	n/p		
Thickness	7-8 mil		
Size	Designed to customer request		
Assembly Method	Multiple techniques including soldering, welding, thermocompression or ultrasonic wire bonding		
Device Design	Monolithic, two terminal triple junction. n/p GalnP ₂ , GaAs, and Ge solar cells interconnected with two tunnel junctions.		
Antireflective Coating	Multi-layer providing low reflectance over wavelength range 0.3 to 1.8µm.		
Solar Cells Compatible with Optional Prismatic Covers and Secondary Optical Elements			
Note: Other Variations Are Available Upon Request			

Temperature Coefficients at 1 Sun

$J_{sc} = 8.2 \ \mu A/cm^2/^{\circ}C$	V _{mp} = -6.7 mV/°C
V_{oc} = -6.4 mV/°C	Efficiency = -0.062 abs%/°C

SO9001:2000 Registered

Winner of Year 2001 R&D 100 Award*





Typical Qualification Test Results (Nominal Degradation)

Test	Description	Results
Humidity	+45°C, 95% RH Min. 30 days	TBD
Thermal Cycle		TBD
Pull Test	Parallel Gap Welded Tabs (Ag, Ag Plated Kovar)	150 g min. 350 g avg. (typical)

*Established in 1963 by Research & Development Magazine, the R&D 100 Awards recognize the 100 most technologically significant new products and processes of the year. Winners are products and processes that can change people's lives for the better, through improvements attributable to significant breakthroughs in technology. Past recipients have included products such as the automated teller machine ('73), the fax machine ('75), the liquid crystal display ('80), Taxol anticancer drug ('93) and high-definition television ('98).



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Typical Cell Electrical Parameters

1000 Suns, AM1.5D (100.0 W/cm²) 25°C

J _{sc} = 11.84 A/cm ²	J _{mp} = 11.27 A/cm ²	
V _{oc} = 3.04 V	V _{mp} = 2.54 V	
P _{mp} = 28.61 W/cm ²	Cff= 81.5 %	
Efficiency= 28.61 %		

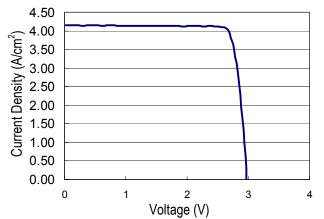
Typical Cell Electrical Parameters

350 Suns, AM1.5D (37.2 W/cm²) 25°C

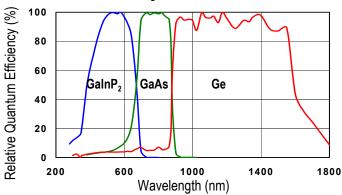
J _{sc} = 4.14 A/cm ²	J _{mp} = 4.05 A/cm ²	
V _{oc} = 2.97 V	V _{mp} = 2.64 V	
P _{mp} = 10.68 W/cm ²	Cff = 86.9 %	
Efficiency = 30.5 %		

Typical Cell Light IV Characteristic

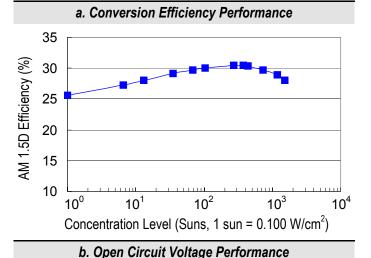
350 Suns, AM1.5D (35 W/cm²) 25°C



Quantum Efficiency

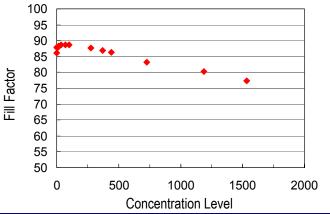


Key Performance Characteristics



 $\overset{3.2}{\underset{2.9}{3.1}}_{3.0}$

c. Fill Factor Performance



The information contained on this sheet is for reference only. Actual specifications for delivered products may vary. 9/12/00

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